



Welcome to [E-XFL.COM](https://www.e-xfl.com)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

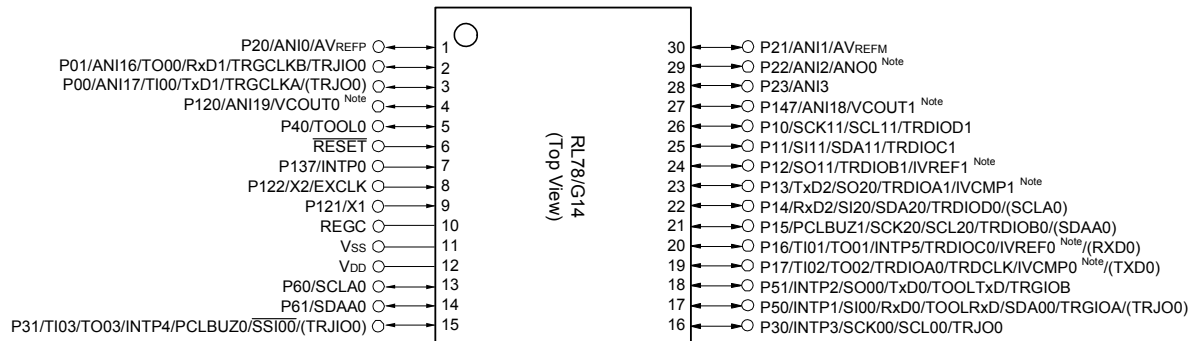
Details

| | |
|----------------------------|---|
| Product Status | Obsolete |
| Core Processor | RL78 |
| Core Size | 16-Bit |
| Speed | 32MHz |
| Connectivity | CSI, I ² C, LINbus, UART/USART |
| Peripherals | DMA, LVD, POR, PWM, WDT |
| Number of I/O | 48 |
| Program Memory Size | 32KB (32K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 4K x 8 |
| RAM Size | 4K x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.6V ~ 5.5V |
| Data Converters | A/D 12x8/10b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 64-LQFP |
| Supplier Device Package | 64-LFQFP (10x10) |
| Purchase URL | https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104lcdfb-x0 |

1.3 Pin Configuration (Top View)

1.3.1 30-pin products

- 30-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch)



Note Mounted on the 96 KB or more code flash memory products.

Caution Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μ F).

Remark 1. For pin identification, see 1.4 Pin Identification.

Remark 2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

[30-pin, 32-pin, 36-pin, 40-pin products (code flash memory 96 KB to 256 KB)]

Caution This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

| Item | | 30-pin | 32-pin | 36-pin | 40-pin |
|------------------------------------|--|--|------------------------|------------------------|--|
| | | R5F104Ax (x = F, G) | R5F104Bx (x = F, G) | R5F104Cx (x = F, G) | R5F104Ex (x = F to H) |
| Code flash memory (KB) | | 96 to 128 | 96 to 128 | 96 to 128 | 96 to 192 |
| Data flash memory (KB) | | 8 | 8 | 8 | 8 |
| RAM (KB) | | 12 to 16 Note | 12 to 16 Note | 12 to 16 Note | 12 to 20 Note |
| Address space | | 1 MB | | | |
| Main system clock | High-speed system clock | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz ($V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ($V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ($V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ($V_{DD} = 1.6$ to 5.5 V) | | | |
| | High-speed on-chip oscillator clock (f_{IH}) | HS (high-speed main) mode: 1 to 32 MHz ($V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ($V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ($V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ($V_{DD} = 1.6$ to 5.5 V) | | | |
| Subsystem clock | | — | | | XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz |
| Low-speed on-chip oscillator clock | | 15 kHz (TYP.): $V_{DD} = 1.6$ to 5.5 V | | | |
| General-purpose register | | 8 bits \times 32 registers (8 bits \times 8 registers \times 4 banks) | | | |
| Minimum instruction execution time | | 0.03125 μ s (High-speed on-chip oscillator clock: $f_{IH} = 32$ MHz operation) | | | |
| | | 0.05 μ s (High-speed system clock: $f_{MX} = 20$ MHz operation) | | | |
| | | — | | | 30.5 μ s (Subsystem clock: $f_{SUB} = 32.768$ kHz operation) |
| Instruction set | | <ul style="list-style-type: none"> • Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits \times 8 bits, 16 bits \times 16 bits), Division (16 bits \div 16 bits, 32 bits \div 32 bits) • Multiplication and Accumulation (16 bits \times 16 bits \div 32 bits) • Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc. | | | |
| I/O port | Total | 26 | 28 | 32 | 36 |
| | CMOS I/O | 21 | 22 | 26 | 28 |
| | CMOS input | 3 | 3 | 3 | 5 |
| | CMOS output | — | — | — | — |
| | N-ch open-drain I/O (6 V tolerance) | 2 | 3 | 3 | 3 |
| Timer | 16-bit timer | 8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel) | | | |
| | Watchdog timer | 1 channel | | | |
| | Real-time clock (RTC) | 1 channel | | | |
| | 12-bit interval timer | 1 channel | | | |
| | Timer output | Timer outputs: 13 channels PWM outputs: 9 channels | | | |
| | RTC output | — | | | 1 • 1 Hz (subsystem clock: $f_{SUB} = 32.768$ kHz) |

(Note is listed on the next page.)

2. ELECTRICAL SPECIFICATIONS (TA = -40 to +85°C)

This chapter describes the following electrical specifications.

Target products A: Consumer applications TA = -40 to +85°C

R5F104xxAxx

D: Industrial applications TA = -40 to +85°C

R5F104xxDxx

G: Industrial applications when TA = -40 to +105°C products is used in the range of TA = -40 to +85°C

R5F104xxGxx

Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

Caution 2. With products not provided with an EVDD0, EVDD1, EVSS0, or EVSS1 pin, replace EVDD0 and EVDD1 with VDD, or replace EVSS0 and EVSS1 with VSS.

Caution 3. The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product in the RL78/G14 User's Manual.

2.3.2 Supply current characteristics

(1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

| Parameter | Symbol | Conditions | | | | | | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------|----------------|-----------------------------------|--|------------------|----------------------|--|------|------|------|------|
| Supply current Note 1 | IDD1 | Operating mode | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.4 | | | mA |
| | | | | | | VDD = 3.0 V | | 2.4 | | | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.1 | | | |
| | | | | | | VDD = 3.0 V | | 2.1 | | | |
| | | | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 5.1 | 8.7 | | mA |
| | | | | | | VDD = 3.0 V | | 5.1 | 8.7 | | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.8 | 8.1 | | |
| | | | | | | VDD = 3.0 V | | 4.8 | 8.1 | | |
| | | | | fHOCO = 48 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.0 | 6.9 | | |
| | | | | | | VDD = 3.0 V | | 4.0 | 6.9 | | |
| | | | | fHOCO = 24 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 3.8 | 6.3 | | |
| | | | | | | VDD = 3.0 V | | 3.8 | 6.3 | | |
| | | | | fHOCO = 16 MHz, fIH = 16 MHz Note 3 | Normal operation | VDD = 5.0 V | | 2.8 | 4.6 | | |
| | | | | | | VDD = 3.0 V | | 2.8 | 4.6 | | |
| | | | LS (low-speed main) mode Note 5 | fHOCO = 8 MHz, fIH = 8 MHz Note 3 | Normal operation | VDD = 3.0 V | | 1.3 | 2.0 | | mA |
| | | | | | | VDD = 2.0 V | | 1.3 | 2.0 | | |
| | | | LV (low-voltage main) mode Note 5 | fHOCO = 4 MHz, fIH = 4 MHz Note 3 | Normal operation | VDD = 3.0 V | | 1.3 | 1.8 | | mA |
| | | | | | | VDD = 2.0 V | | 1.3 | 1.8 | | |
| | | | HS (high-speed main) mode Note 5 | fMX = 20 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 3.3 | 5.3 | | mA |
| | | | | | | Resonator connection | | 3.4 | 5.5 | | |
| | | | | fMX = 20 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 3.3 | 5.3 | | |
| | | | | | | Resonator connection | | 3.4 | 5.5 | | |
| | | | | fMX = 10 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 2.0 | 3.1 | | |
| | | | | | | Resonator connection | | 2.1 | 3.2 | | |
| | | | | fMX = 10 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 2.0 | 3.1 | | |
| | | | | | | Resonator connection | | 2.1 | 3.2 | | |
| | | | LS (low-speed main) mode Note 5 | fMX = 8 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 1.2 | 1.9 | | mA |
| | | | | | | Resonator connection | | 1.2 | 2.0 | | |
| | | | | fMX = 8 MHz Note 2, VDD = 2.0 V | Normal operation | Square wave input | | 1.2 | 1.9 | | |
| | | | | | | Resonator connection | | 1.2 | 2.0 | | |
| | | | Subsystem clock operation | fSUB = 32.768 kHz Note 4 TA = -40°C | Normal operation | Square wave input | | 4.7 | 6.1 | | μA |
| | | | | | | Resonator connection | | 4.7 | 6.1 | | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +25°C | Normal operation | Square wave input | | 4.7 | 6.1 | | |
| | | | | | | Resonator connection | | 4.7 | 6.1 | | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +50°C | Normal operation | Square wave input | | 4.8 | 6.7 | | |
| | | | | | | Resonator connection | | 4.8 | 6.7 | | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +70°C | Normal operation | Square wave input | | 4.8 | 7.5 | | |
| | | | | | | Resonator connection | | 4.8 | 7.5 | | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +85°C | Normal operation | Square wave input | | 5.4 | 8.9 | | |
| | | | | | | Resonator connection | | 5.4 | 8.9 | | |

(Notes and Remarks are listed on the next page.)

- Note 5.** Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{WDT} when the watchdog timer is in operation.
- Note 6.** Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of I_{DD1} or I_{DD2} and I_{ADC} when the A/D converter operates in an operation mode or the HALT mode.
- Note 7.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{LVD} when the LVD circuit is in operation.
- Note 8.** Current flowing during programming of the data flash.
- Note 9.** Current flowing during self-programming.
- Note 10.** For shift time to the SNOOZE mode, see **23.3.3 SNOOZE mode** in the RL78/G14 User's Manual.
- Note 11.** Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of I_{DD1} or I_{DD2} and I_{DAC} when the D/A converter operates in an operation mode or the HALT mode.
- Note 12.** Current flowing only to the comparator circuit. The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2}, or I_{DD3} and I_{CMP} when the comparator circuit is in operation.
- Note 13.** A comparator and D/A converter are provided in products with 96 KB or more code flash memory.

Remark 1. f_{IL}: Low-speed on-chip oscillator clock frequency

Remark 2. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

Remark 3. f_{CLK}: CPU/peripheral hardware clock frequency

Remark 4. Temperature condition of the TYP. value is T_A = 25°C

(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)**(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | LS (low-speed main) mode | | LV (low-voltage main) mode | | Unit |
|--|--|---|----------------------------|---------------------------|------|----------------------------|------|----------------------------|------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} | 2.7 V ≤ EVDD0 ≤ 5.5 V | 125 | | 500 | | 1000 | | ns |
| | | | 2.4 V ≤ EVDD0 ≤ 5.5 V | 250 | | 500 | | 1000 | | ns |
| | | | 1.8 V ≤ EVDD0 ≤ 5.5 V | 500 | | 500 | | 1000 | | ns |
| | | | 1.7 V ≤ EVDD0 ≤ 5.5 V | 1000 | | 1000 | | 1000 | | ns |
| | | | 1.6 V ≤ EVDD0 ≤ 5.5 V | — | | 1000 | | 1000 | | ns |
| SCKp high-/low-level width | t _{KH1} , t _{KL1} | 4.0 V ≤ EVDD0 ≤ 5.5 V | t _{KCY1} /2 - 12 | | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | t _{KCY1} /2 - 18 | | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | t _{KCY1} /2 - 38 | | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | t _{KCY1} /2 - 50 | | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | t _{KCY1} /2 - 100 | | | t _{KCY1} /2 - 100 | | t _{KCY1} /2 - 100 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | — | | | t _{KCY1} /2 - 100 | | t _{KCY1} /2 - 100 | | ns |
| Slp setup time (to SCKp↑) Note 1 | t _{SIK1} | 4.0 V ≤ EVDD0 ≤ 5.5 V | 44 | | | 110 | | 110 | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | 44 | | | 110 | | 110 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | 75 | | | 110 | | 110 | | ns |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | 110 | | | 110 | | 110 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | 220 | | | 220 | | 220 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | — | | | 220 | | 220 | | ns |
| Slp hold time (from SCKp↑) Note 2 | t _{KSI1} | 1.7 V ≤ EVDD0 ≤ 5.5 V | 19 | | | 19 | | 19 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | — | | | 19 | | 19 | | ns |
| Delay time from SCKp↓ to SOp output Note 3 | t _{KSO1} | 1.7 V ≤ EVDD0 ≤ 5.5 V C = 30 pF Note 4 | | 25 | | 25 | | 25 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V C = 30 pF Note 4 | | — | | 25 | | 25 | | ns |

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)**(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | LS (low-speed main) mode | | LV (low-voltage main) mode | | Unit |
|-----------------------|-------------------|--|----------------------------|------|----------------------------|------|----------------------------|------|------|
| | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 300 | | 1150 | | 1150 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 500 | | 1150 | | 1150 | | ns |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V <i>Note</i> , C _b = 30 pF, R _b = 5.5 kΩ | 1150 | | 1150 | | 1150 | | ns |
| SCKp high-level width | t _{KH1} | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 75 | | t _{KCY1} /2 - 75 | | t _{KCY1} /2 - 75 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 170 | | t _{KCY1} /2 - 170 | | t _{KCY1} /2 - 170 | | ns |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V <i>Note</i> , C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 458 | | t _{KCY1} /2 - 458 | | t _{KCY1} /2 - 458 | | ns |
| SCKp low-level width | t _{KL1} | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 12 | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 18 | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V <i>Note</i> , C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | t _{KCY1} /2 - 50 | | ns |

Note Use it with EVDD0 ≥ V_b.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

2.5.2 Serial interface IICA

(1) I²C standard mode

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | LS (low-speed main) mode | | LV (low-voltage main) mode | | Unit |
|---------------------------------|----------------------|--|-----------------------|---------------------------|------|--------------------------|------|----------------------------|------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCLA0 clock frequency | f _{SCL} | Standard mode: f _{CLK} ≥ 1 MHz | 2.7 V ≤ EVDD0 ≤ 5.5 V | 0 | 100 | 0 | 100 | 0 | 100 | kHz |
| | | | 1.8 V ≤ EVDD0 ≤ 5.5 V | 0 | 100 | 0 | 100 | 0 | 100 | kHz |
| | | | 1.7 V ≤ EVDD0 ≤ 5.5 V | 0 | 100 | 0 | 100 | 0 | 100 | kHz |
| | | | 1.6 V ≤ EVDD0 ≤ 5.5 V | — | | 0 | 100 | 0 | 100 | kHz |
| Setup time of restart condition | t _{SU: STA} | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 4.7 | | 4.7 | | μs |
| Hold time ^{Note 1} | t _{HD: STA} | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 4.0 | | 4.0 | | μs |
| Hold time when SCLA0 = "L" | t _{LOW} | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 4.7 | | 4.7 | | 4.7 | | μs |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 4.7 | | 4.7 | | μs |
| Hold time when SCLA0 = "H" | t _{HIGH} | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 4.0 | | 4.0 | | 4.0 | | μs |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 4.0 | | 4.0 | | μs |

(Notes, Caution, and Remark are listed on the next page.)

- (3) When reference voltage (+) = V_{DD} (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V_{SS} (ADREFM = 0), target pin: ANI0 to ANI14, ANI16 to ANI20, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V, Reference voltage (+) = V_{DD}, Reference voltage (-) = V_{SS})

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|--|----------------------------|------|-------------------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | 1.2 | ±7.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | 1.2 | ±10.5 | LSB |
| Conversion time | t _{CONV} | 10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI20 | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.1875 | | 39 | μs |
| | | | 1.8 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V | 57 | | 95 | μs |
| | | 10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.375 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.5625 | | 39 | μs |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| | | | | | | | |
| Zero-scale error Notes 1, 2 | E _{zs} | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±0.85 | %FSR |
| Full-scale error Notes 1, 2 | E _{fs} | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±0.85 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±4.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±6.5 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±2.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±2.5 | LSB |
| Analog input voltage | V _{AIN} | ANI0 to ANI14 | | 0 | | V _{DD} | V |
| | | ANI16 to ANI20 | | 0 | | EV _{DD0} | V |
| | | Internal reference voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{BGR} Note 4 | | | V |
| | | Temperature sensor output voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{TMPS25} Note 4 | | | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (% FSR) to the full-scale value.

Note 3. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

Note 4. Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(5/5)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-----------------------------|-------------------|--|--|---------------------------------------|------|------|-----------|
| Input leakage current, high | ILI _{H1} | P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147 | V _I = EV _{DD0} | | | | 1 μA |
| | ILI _{H2} | P20 to P27, P137, P150 to P156, <u>RESET</u> | V _I = V _{DD} | | | | 1 μA |
| | ILI _{H3} | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS) | V _I = V _{DD} | In input port or external clock input | | | 1 μA |
| | | | | In resonator connection | | | 10 μA |
| Input leakage current, low | ILI _{L1} | P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147 | V _I = EV _{SS0} | | | | -1 μA |
| | ILI _{L2} | P20 to P27, P137, P150 to P156, <u>RESET</u> | V _I = V _{SS} | | | | -1 μA |
| | ILI _{L3} | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS) | V _I = V _{SS} | In input port or external clock input | | | -1 μA |
| | | | | In resonator connection | | | -10 μA |
| On-chip pull-up resistance | R _U | P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147 | V _I = EV _{SS0} , In input port | | 10 | 20 | 100 kΩ |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

3.3.2 Supply current characteristics

(1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

| Parameter | Symbol | Conditions | | | | | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------|----------------|----------------------------------|---|------------------|----------------------|------|------|------|------|
| Supply current Note 1 | IDD1 | Operating mode | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.4 | | mA |
| | | | | | | VDD = 3.0 V | | 2.4 | | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.1 | | |
| | | | | | | VDD = 3.0 V | | 2.1 | | |
| | | | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 5.1 | 9.3 | mA |
| | | | | | | VDD = 3.0 V | | 5.1 | 9.3 | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.8 | 8.7 | |
| | | | | | | VDD = 3.0 V | | 4.8 | 8.7 | |
| | | | | fHOCO = 48 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.0 | 7.3 | |
| | | | | | | VDD = 3.0 V | | 4.0 | 7.3 | |
| | | | | fHOCO = 24 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 3.8 | 6.7 | |
| | | | | | | VDD = 3.0 V | | 3.8 | 6.7 | |
| | | | | fHOCO = 16 MHz, fIH = 16 MHz Note 3 | Normal operation | VDD = 5.0 V | | 2.8 | 4.9 | |
| | | | | | | VDD = 3.0 V | | 2.8 | 4.9 | |
| | | | HS (high-speed main) mode Note 5 | fMX = 20 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | mA |
| | | | | | | Resonator connection | | 3.4 | 5.8 | |
| | | | | fMX = 20 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | |
| | | | | | | Resonator connection | | 3.4 | 5.8 | |
| | | | | fMX = 10 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | | fMX = 10 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | Subsystem clock operation | fSUB = 32.768 kHz Note 4 TA = -40°C | Normal operation | Square wave input | | 4.7 | 6.1 | μA |
| | | | | | | Resonator connection | | 4.7 | 6.1 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +25°C | Normal operation | Square wave input | | 4.7 | 6.1 | |
| | | | | | | Resonator connection | | 4.7 | 6.1 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +50°C | Normal operation | Square wave input | | 4.8 | 6.7 | |
| | | | | | | Resonator connection | | 4.8 | 6.7 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +70°C | Normal operation | Square wave input | | 4.8 | 7.5 | |
| | | | | | | Resonator connection | | 4.8 | 7.5 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +85°C | Normal operation | Square wave input | | 5.4 | 8.9 | |
| | | | | | | Resonator connection | | 5.4 | 8.9 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +105°C | Normal operation | Square wave input | | 7.2 | 21.0 | |
| | | | | | | Resonator connection | | 7.3 | 21.1 | |

(Notes and Remarks are listed on the next page.)

3.4 AC Characteristics

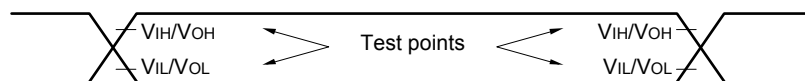
($T_A = -40$ to $+105^\circ\text{C}$, $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$, $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$)

| Items | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit |
|--|--------------|-------------------------------------|---------------------------|-----------------------|---------------------|------|------|------|
| Instruction cycle (minimum instruction execution time) | Tcy | Main system clock (fMAIN) operation | HS (high-speed main) mode | 2.7 V ≤ VDD ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| | | Subsystem clock (fSUB) operation | | 2.4 V ≤ VDD ≤ 5.5 V | 28.5 | 30.5 | 31.3 | μs |
| | | In the self-programming mode | HS (high-speed main) mode | 2.7 V ≤ VDD ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| External system clock frequency | fEX | 2.7 V ≤ VDD ≤ 5.5 V | | | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD ≤ 2.7 V | | | 1.0 | | 16.0 | MHz |
| | fEXS | | | | 32 | | 35 | kHz |
| External system clock input high-level width, low-level width | tEXH, | 2.7 V ≤ VDD ≤ 5.5 V | | | 24 | | | ns |
| | tEXL | 2.4 V ≤ VDD ≤ 2.7 V | | | 30 | | | ns |
| | tEXHS, tEXLS | | | | 13.7 | | | μs |
| Ti00 to Ti03, Ti10 to Ti13 input high-level width, low-level width | tTih, tTil | | | | 1/fMCK + 10 Note | | | ns |
| Timer RJ input cycle | fc | TRJIO | | 2.7 V ≤ EVDD0 ≤ 5.5 V | 100 | | | ns |
| | | | | 2.4 V ≤ EVDD0 < 2.7 V | 300 | | | ns |
| Timer RJ input high-level width, low-level width | tTjH, tTjL | TRJIO | | 2.7 V ≤ EVDD0 ≤ 5.5 V | 40 | | | ns |
| | | | | 2.4 V ≤ EVDD0 < 2.7 V | 120 | | | ns |

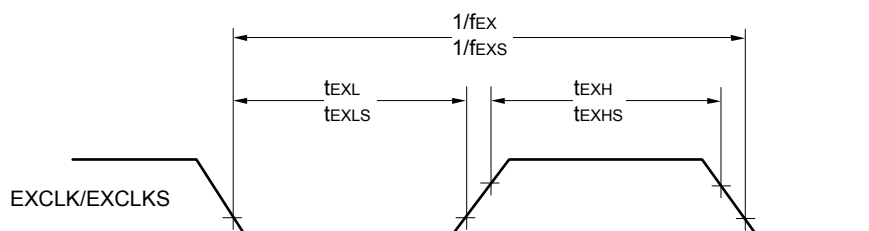
Note The following conditions are required for low voltage interface when $\text{EVDD0} < \text{VDD}$
 $2.4\text{ V} \leq \text{EVDD0} < 2.7\text{ V}$: MIN. 125 ns

Remark f_{MCK} : Timer array unit operation clock frequency
 (Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

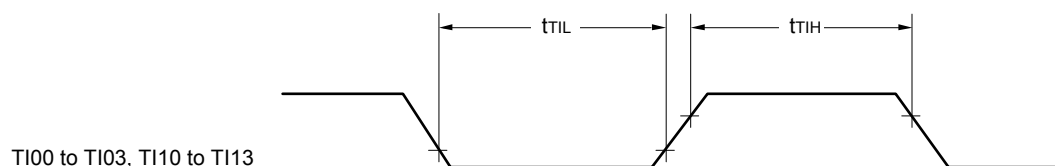
AC Timing Test Points



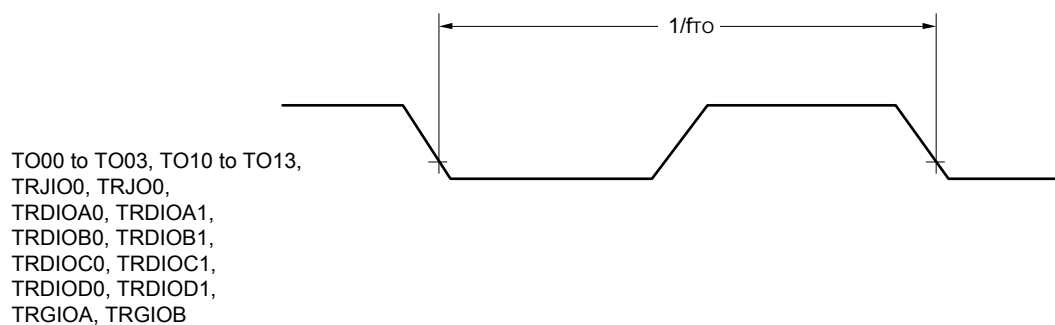
External System Clock Timing



TI/TO Timing



TI00 to TI03, TI10 to TI13



TO00 to TO03, TO10 to TO13,
TRJIO0, TRJO0,
TRDIOA0, TRDIOA1,
TRDIOB0, TRDIOB1,
TRDIOC0, TRDIOC1,
TRDIOD0, TRDIOD1,
TRGIOA, TRGIOB

(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|--|------------|-----------------------|-----------------------|---------------------------|--------------|------|
| | | | | MIN. | MAX. | |
| SCKp cycle time Note 5 | tkCY2 | 4.0 V ≤ EVDD0 ≤ 5.5 V | 20 MHz < fMCK | 16/fMCK | | ns |
| | | | fMCK ≤ 20 MHz | 12/fMCK | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | 16 MHz < fMCK | 16/fMCK | | ns |
| | | | fMCK ≤ 16 MHz | 12/fMCK | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | 12/fMCK and 1000 | | ns |
| SCKp high-/low-level width | tkH2, tkL2 | 4.0 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 14 | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 16 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 36 | | ns |
| Slp setup time (to SCKp↑) Note 1 | tSIK2 | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 40 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 60 | | ns |
| Slp hold time (from SCKp↑) Note 2 | tSIH2 | | | 1/fMCK + 62 | | ns |
| Delay time from SCKp↓ to SOp output Note 3 | tKS02 | C = 30 pF Note 4 | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 66 | ns |
| | | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 113 | ns |

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SOp output lines.

Note 5. The maximum transfer rate when using the SNOOZE mode is 1 Mbps.

Caution Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1),
n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

Remark 2. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
n: Channel number (mn = 00 to 03, 10 to 13))

(4) During communication at same potential (simplified I²C mode)**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-------------------------------|----------------------|---|---------------------------------|------------|------|
| | | | MIN. | MAX. | |
| SCLr clock frequency | f _{SCL} | 2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ | | 100 Note 1 | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ | 4600 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ | 4600 | | ns |
| Data setup time (reception) | t _{SU: DAT} | 2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ | 1/f _{MCK} + 220 Note 2 | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ | 1/f _{MCK} + 580 Note 2 | | ns |
| Data hold time (transmission) | t _{HD: DAT} | 2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ | 0 | 770 | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ | 0 | 1420 | ns |

Note 1. The value must also be equal to or less than f_{MCK}/4.**Note 2.** Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

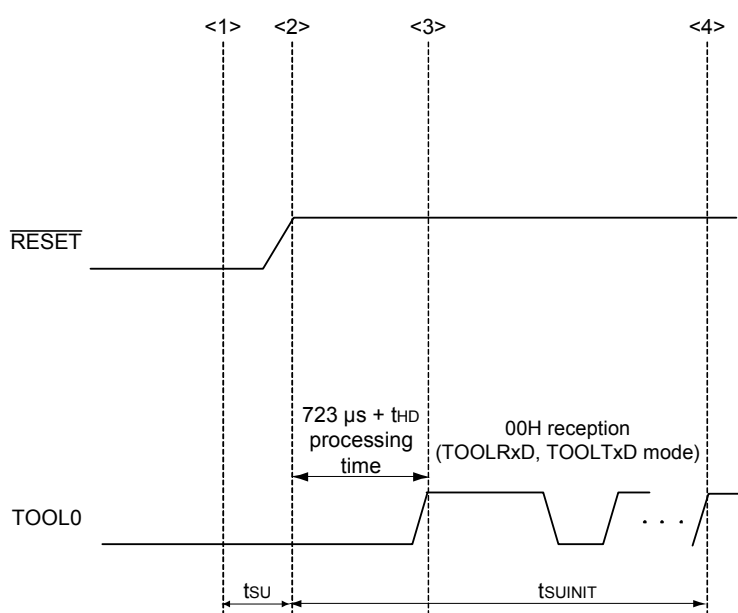
Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance (for the 30- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

3.10 Timing of Entry to Flash Memory Programming Modes

($T_A = -40$ to $+105^\circ\text{C}$, $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$, $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|---------------------|--|------|------|------|---------------|
| How long from when an external reset ends until the initial communication settings are specified | t_{SUINIT} | POR and LVD reset must end before the external reset ends. | | | 100 | ms |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends | t_{SU} | POR and LVD reset must end before the external reset ends. | 10 | | | μs |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | t_{HD} | POR and LVD reset must end before the external reset ends. | 1 | | | ms |



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUINIT} : The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

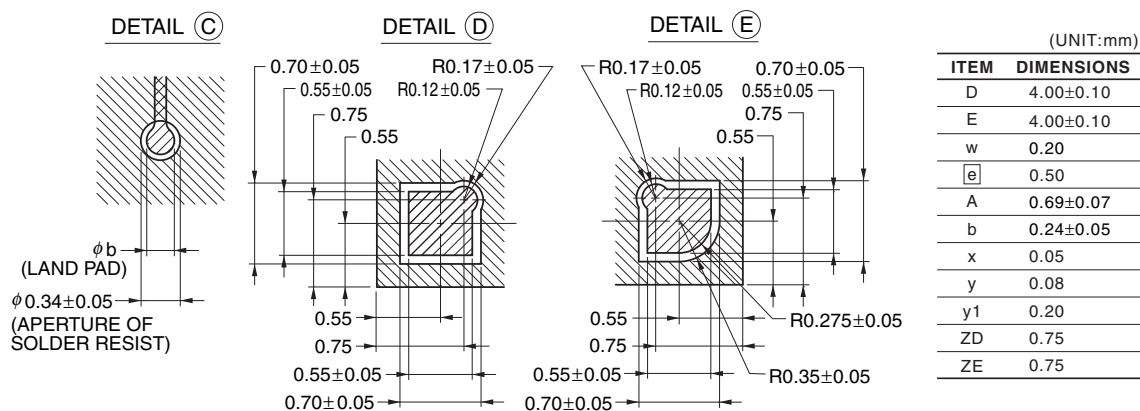
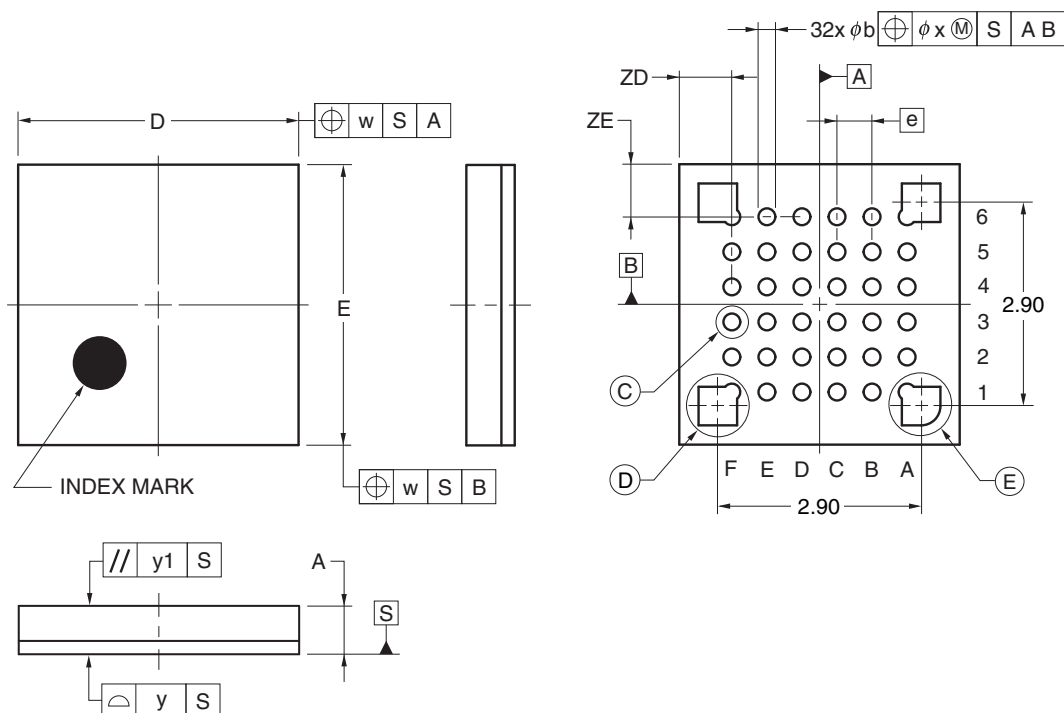
t_{SU} : How long from when the TOOL0 pin is placed at the low level until a pin reset ends

t_{HD} : How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

4.3 36-pin products

R5F104CAALA, R5F104CCALA, R5F104CDALA, R5F104CEALA, R5F104CFALA, R5F104CGALA
R5F104CAGLA, R5F104CCGLA, R5F104CDGLA, R5F104CEGLA, R5F104CFGLA, R5F104CGGLA

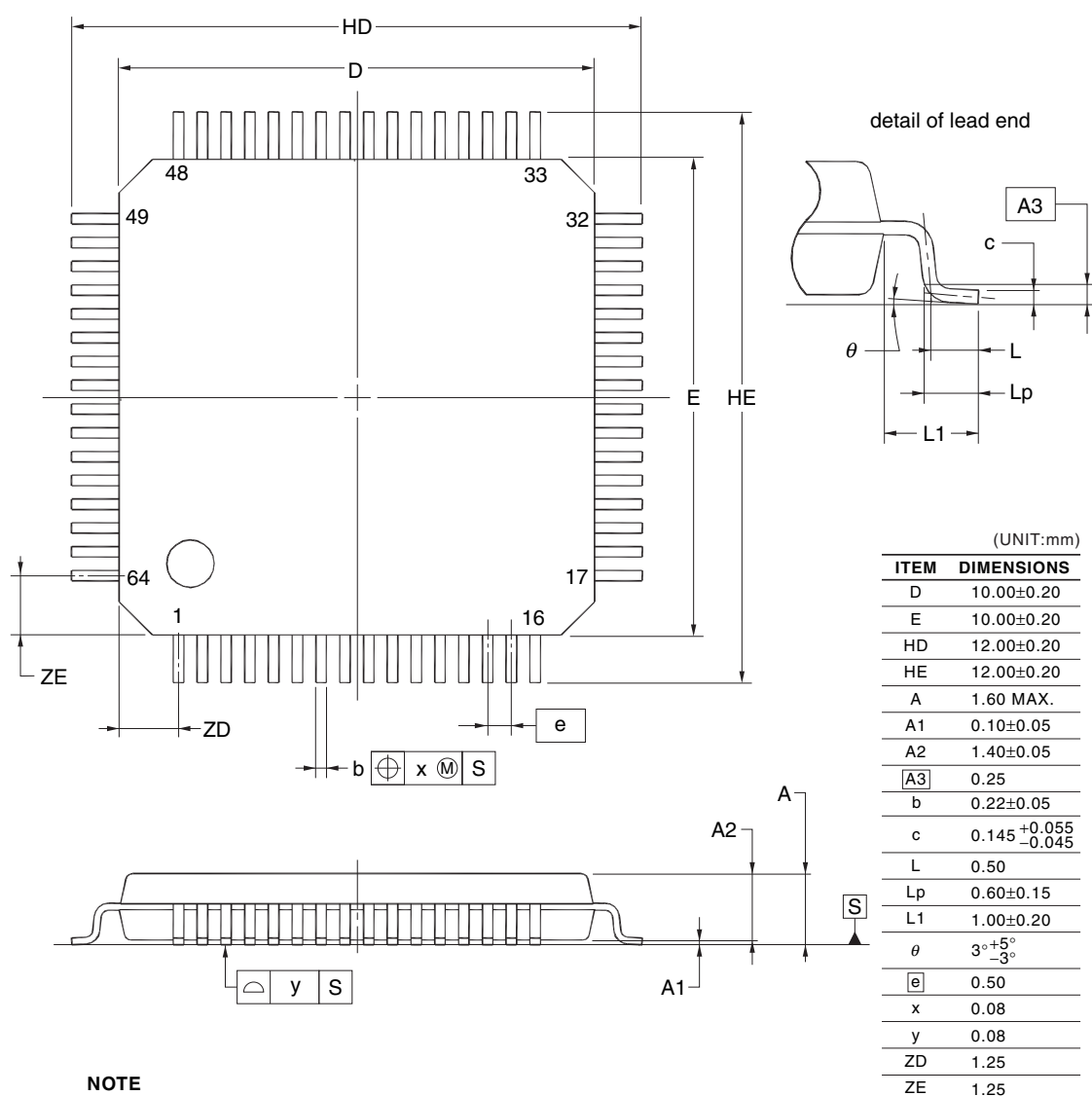
| JEITA Package Code | RENESAS Code | Previous Code | MASS (TYP.) [g] |
|--------------------|--------------|----------------|-----------------|
| P-WFLGA36-4x4-0.50 | PWLG0036KA-A | P36FC-50-AA4-2 | 0.023 |



© 2012 Renesas Electronics Corporation. All rights reserved.

R5F104LCAFB, R5F104LDAFB, R5F104LEAFB, R5F104LFAFB, R5F104LGAFB, R5F104LHAFB,
 R5F104LJAFB
 R5F104LCDFB, R5F104LDDFB, R5F104LEDFB, R5F104LFDFB, R5F104LGDFB, R5F104LHDFB,
 R5F104LJDFB
 R5F104LCGFB, R5F104LDGFB, R5F104LEGFB, R5F104LFGFB, R5F104LGGFB, R5F104LHGFB,
 R5F104LJGFB

| JEITA Package Code | RENESAS Code | Previous Code | MASS (TYP.) [g] |
|----------------------|--------------|----------------|-----------------|
| P-LFQFP64-10x10-0.50 | PLQP0064KF-A | P64GB-50-UEU-2 | 0.35 |



NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

| | |
|------------------|--------------------|
| REVISION HISTORY | RL78/G14 Datasheet |
|------------------|--------------------|

| Rev. | Date | Description | |
|------|--------------|---|--|
| | | Page | Summary |
| 3.20 | Jan 05, 2015 | p.135, 137, 139, 141, 143, 145 p.197 | Modification of specifications in 3.3.2 Supply current characteristics Modification of part number in 4.7 52-pin products |
| 3.30 | Aug 12, 2016 | p.143, 145 | Addition of maximum values in (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products of 3.3.2 Supply current characteristics |

SuperFlash is a registered trademark of Silicon Storage Technology, Inc. in several countries including the United States and Japan.

Caution: This product uses SuperFlash® technology licensed from Silicon Storage Technology, Inc.

All trademarks and registered trademarks are the property of their respective owners.

NOTES FOR CMOS DEVICES

- (1) **VOLTAGE APPLICATION WAVEFORM AT INPUT PIN:** Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (MAX) and V_{IH} (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (MAX) and V_{IH} (MIN).
- (2) **HANDLING OF UNUSED INPUT PINS:** Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.
- (3) **PRECAUTION AGAINST ESD:** A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.
- (4) **STATUS BEFORE INITIALIZATION:** Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.
- (5) **POWER ON/OFF SEQUENCE:** In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current. The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.
- (6) **INPUT OF SIGNAL DURING POWER OFF STATE :** Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.